

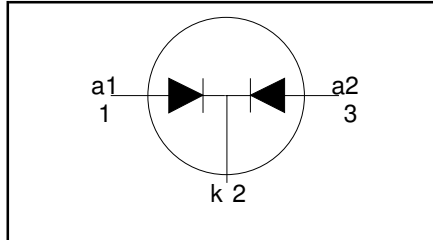
Dual rectifier diodes ultrafast

BYV44 series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 300 \text{ V} / 400 \text{ V} / 500 \text{ V}$$

$$V_F \leq 1.12 \text{ V}$$

$$I_{O(AV)} = 30 \text{ A}$$

$$t_{rr} \leq 60 \text{ ns}$$

GENERAL DESCRIPTION

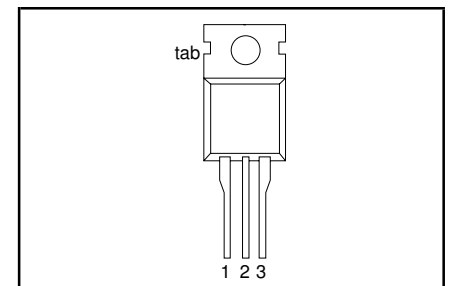
Dual, common cathode, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV44 series is supplied in the conventional leaded SOT78 (TO220AB) package.

PINNING

PIN	DESCRIPTION
1	anode 1
2	cathode
3	anode 2
tab	cathode

SOT78 (TO220AB)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V_{RRM}	Peak repetitive reverse voltage	BYV44 $T_{mb} \leq 136^\circ\text{C}$ square wave; $\delta = 0.5$; $T_{mb} \leq 94^\circ\text{C}$ $t = 25 \mu\text{s}$; $\delta = 0.5$; $T_{mb} \leq 94^\circ\text{C}$ $t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ sinusoidal; with reapplied $V_{RRM(max)}$	-	-300	-400	-500	V
V_{RWM}	Crest working reverse voltage		-	300	400	500	V
V_R	Continuous reverse voltage		-	300	400	500	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting) ¹		-	30			A
I_{FRM}	Repetitive peak forward current per diode		-	30			A
I_{FSM}	Non-repetitive peak forward current per diode.		-	150			A
			-	160			A
T_{stg}	Storage temperature		-40	150			$^\circ\text{C}$
T_j	Operating junction temperature		-	150			$^\circ\text{C}$

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-hs}$	Thermal resistance junction to heatsink	per diode	-	-	2.4	K/W
$R_{th j-a}$	Thermal resistance junction to ambient	both diodes conducting in free air.	-	-	1.4	K/W
			-	60	-	K/W

¹ Neglecting switching and reverse current losses.

For output currents in excess of 20 A, the cathode connection should be made to the metal mounting tab.

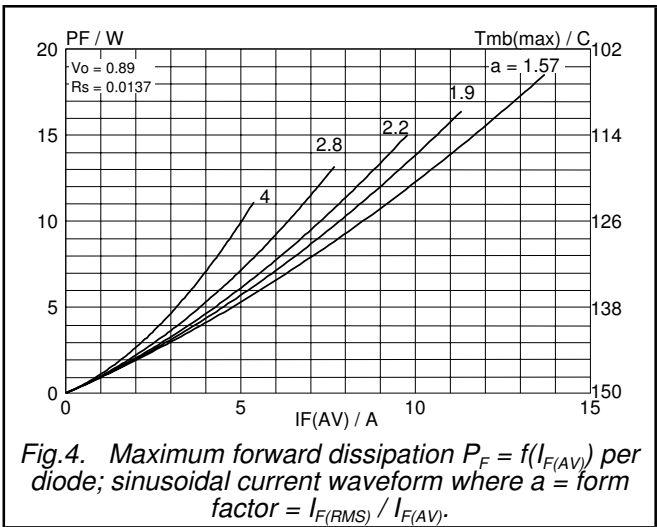
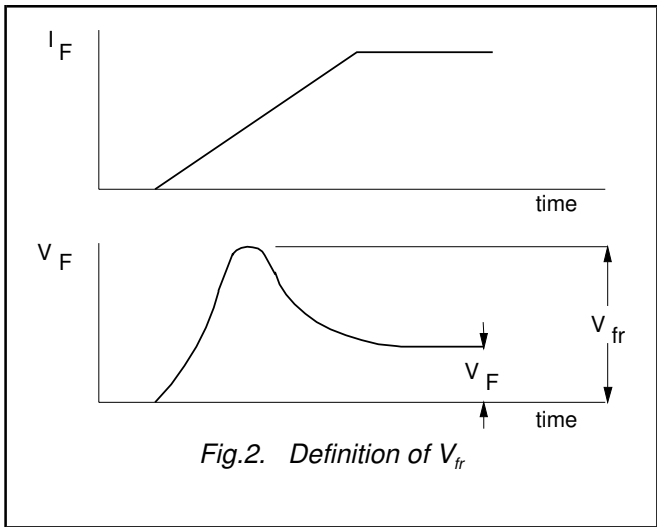
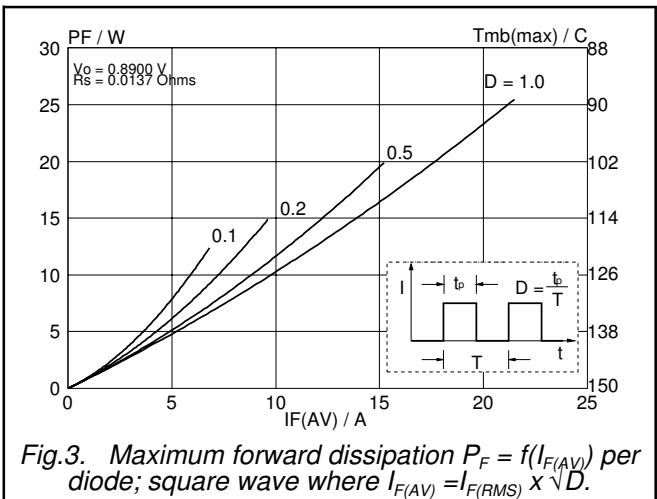
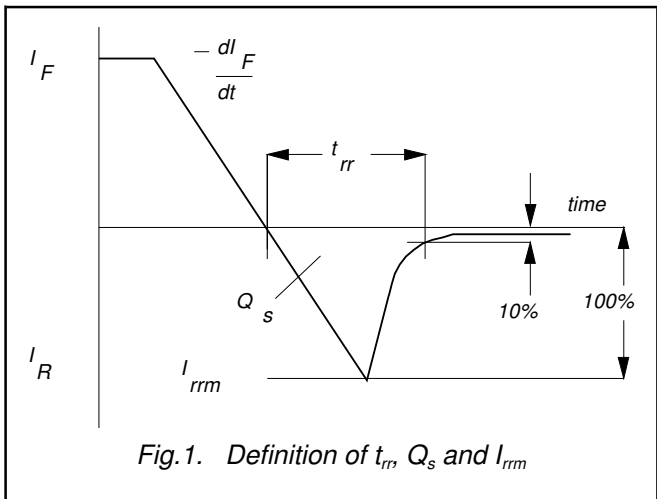
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ELECTRICAL CHARACTERISTICS

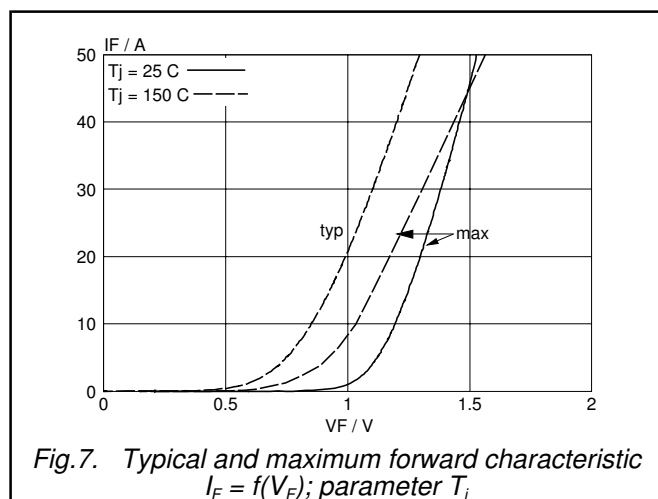
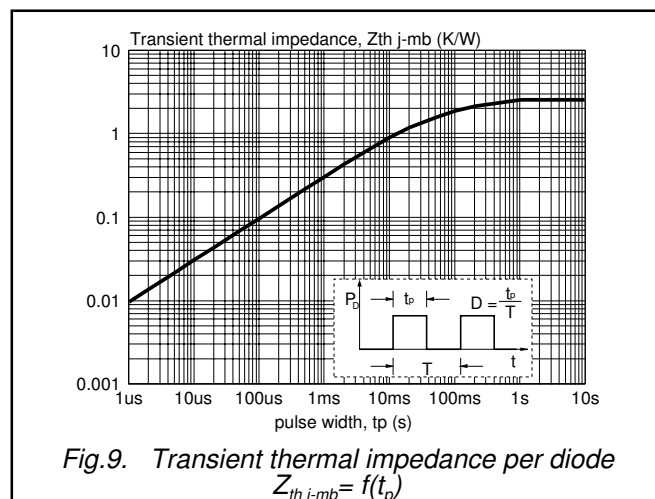
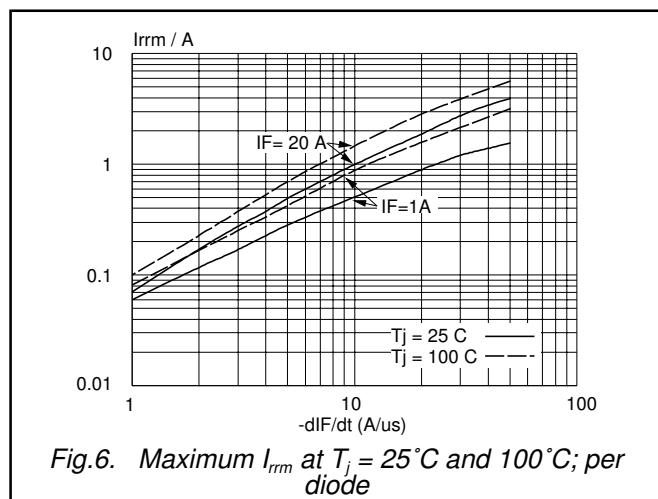
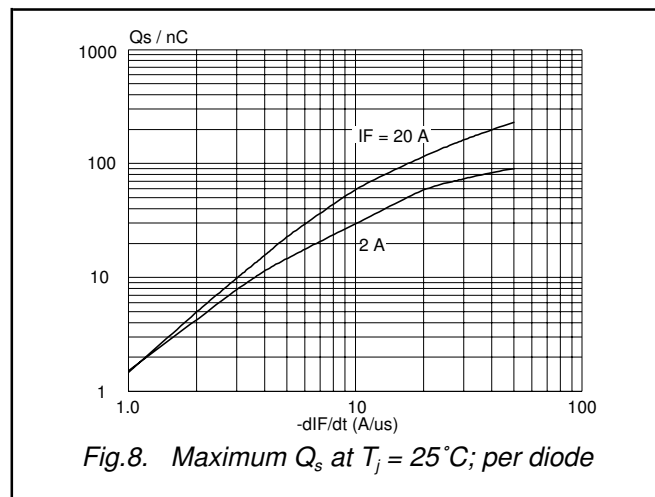
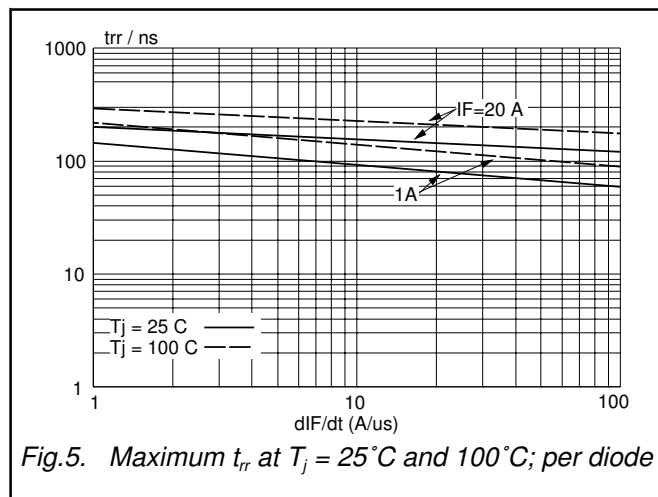
characteristics are per diode at $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 15\text{ A}$; $T_j = 150\text{ }^{\circ}\text{C}$	-	0.95	1.12	V
		$I_F = 15\text{ A}$	-	1.08	1.25	V
		$I_F = 30\text{ A}$	-	1.15	1.36	V
I_R	Reverse current	$V_R = V_{RRM}$	-	10	50	μA
		$V_R = V_{RRM}$; $T_j = 100\text{ }^{\circ}\text{C}$	-	0.3	0.8	mA
Q_s	Reverse recovery charge	$I_F = 2\text{ A}$ to $V_R \geq 30\text{ V}$; $di_F/dt = 20\text{ A}/\mu\text{s}$	-	40	60	nC
t_{rr}	Reverse recovery time	$I_F = 1\text{ A}$ to $V_R \geq 30\text{ V}$; $di_F/dt = 100\text{ A}/\mu\text{s}$	-	50	60	ns
I_{rrm}	Peak reverse recovery current	$I_F = 10\text{ A}$ to $V_R \geq 30\text{ V}$; $di_F/dt = 50\text{ A}/\mu\text{s}$; $T_j = 100\text{ }^{\circ}\text{C}$	-	4.2	5.2	A
V_{fr}	Forward recovery voltage	$I_F = 10\text{ A}$; $di_F/dt = 10\text{ A}/\mu\text{s}$	-	2.5	-	V



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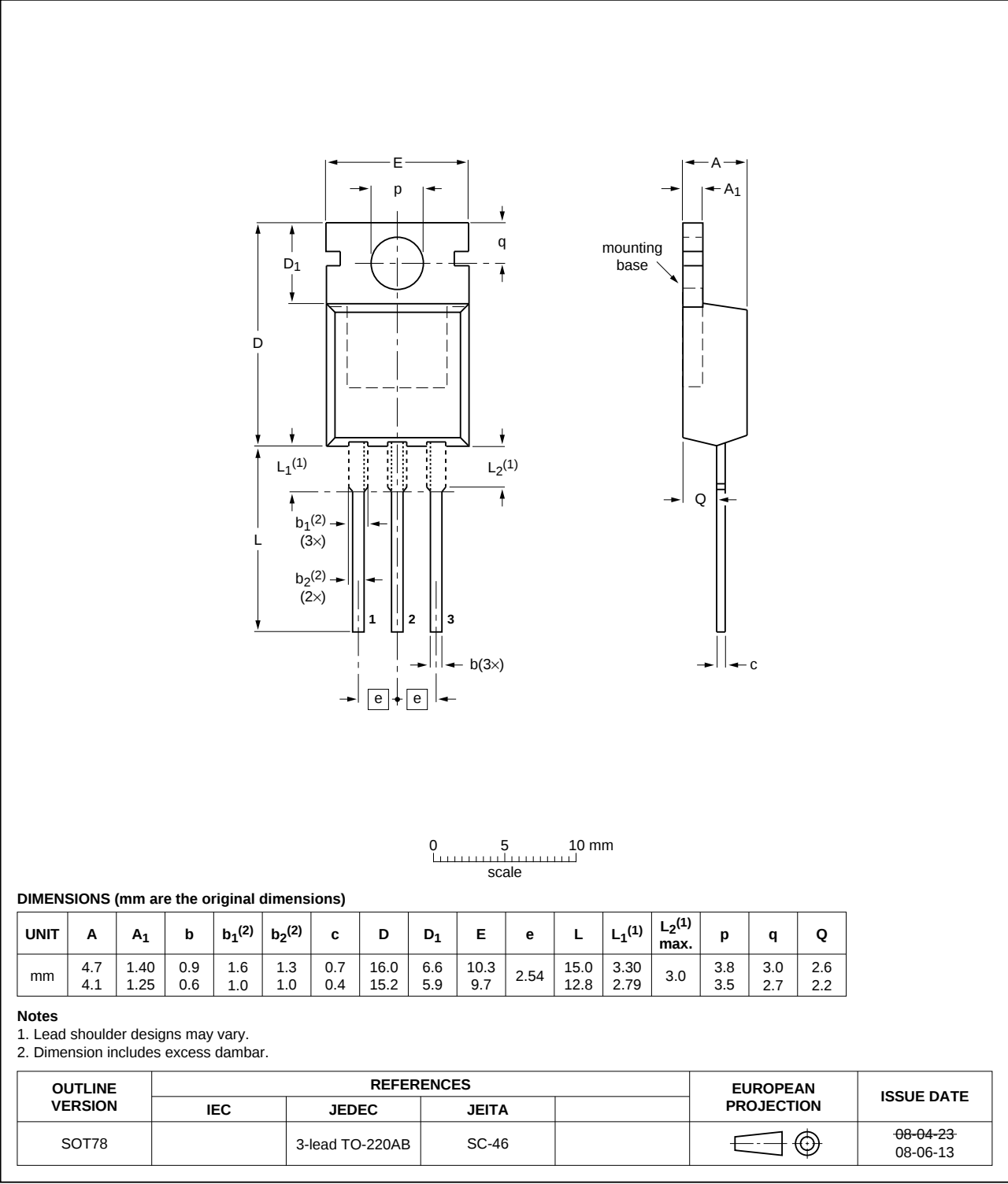
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MECHANICAL DATA

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ween-semi.com>.

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